

ZXMP4A57E6

40V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

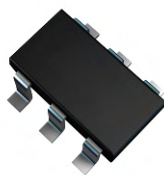
$V_{(BR)DSS}$	$R_{DS(on)}$ max	I_D max $T_A = 25^\circ\text{C}$
-40V	80m Ω @ $V_{GS} = -10\text{V}$	-3.7 A
	150m Ω @ $V_{GS} = -4.5\text{V}$	-2.8 A

Description and Applications

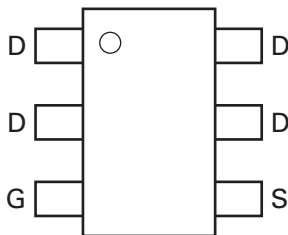
This MOSFET has been designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor control
- DC-DC Converters
- Power management functions
- Uninterrupted power supply

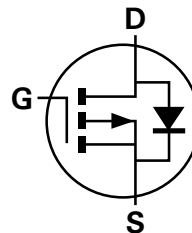
SOT26



Top View



Top View
Pin-Out



Equivalent Circuit

Features and Benefits

- Fast switching speed
- Low gate drive
- Low input capacitance
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

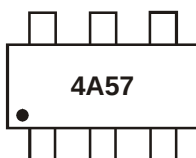
- Case: SOT26
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208
- Weight 0.018 grams (approximate)

Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXMP4A57E6TA	4A57	7	8	3,000

- Notes:
1. No purposefully added lead
 2. Diodes Inc's "Green" policy can be found on our website at <http://www.diodes.com>.
 3. For packaging details, go to our website at <http://www.diodes.com>.

Marking Information



4A57 = Product Type Marking Code

Maximum Ratings @T_A = 25°C unless otherwise specified

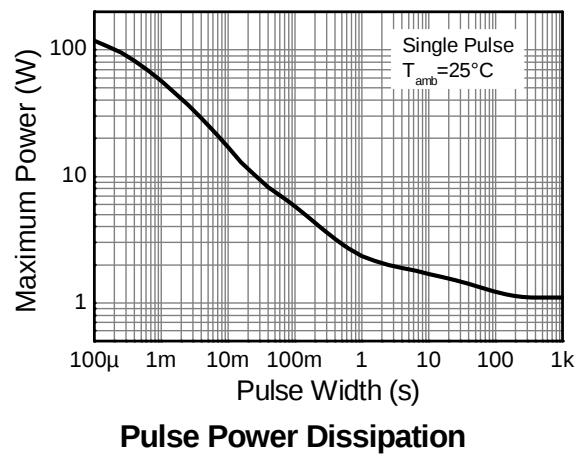
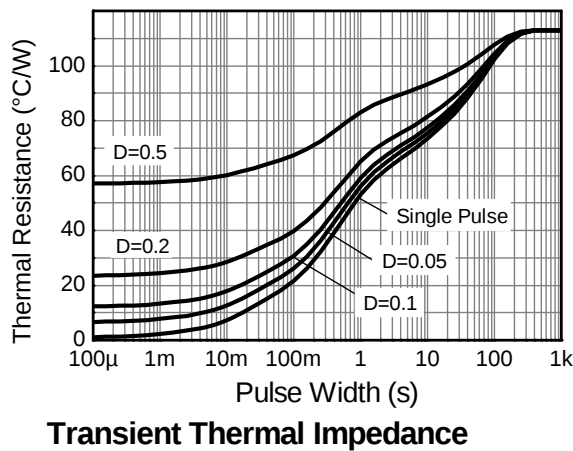
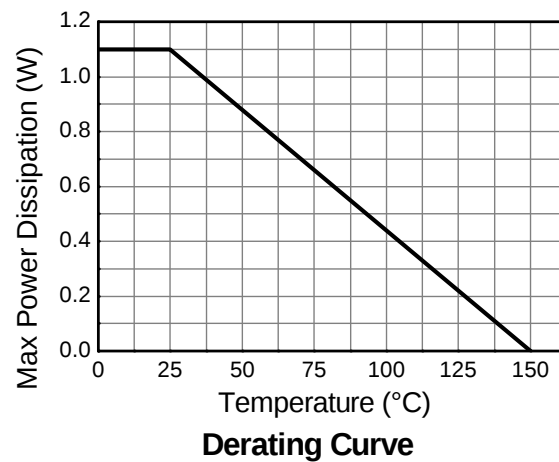
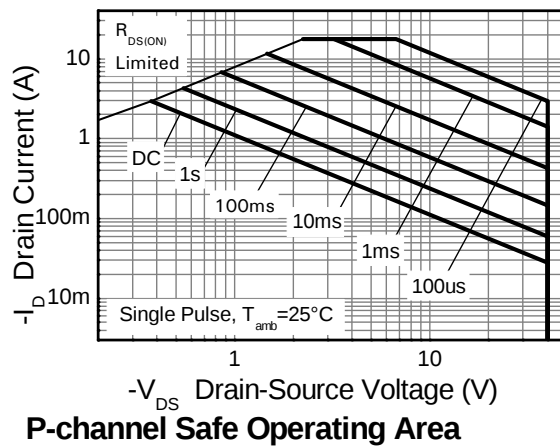
Characteristic			Symbol	Value	Unit
Drain-Source voltage			V _{DSS}	-40	V
Gate-Source voltage			V _{GS}	±20	V
Continuous Drain current	V _{GS} = 10V	(Note 5)	I _D	-3.7	A
		T _A = 70°C (Note 5)		-2.9	
		(Note 4)		-2.9	
Pulsed Drain current	V _{GS} = 10V	(Note 6)	I _{DM}	-18	A
Continuous Source current (Body diode)			I _S	-2.6	A
Pulsed Source current (Body diode)			I _{SM}	-18	A

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Power dissipation	(Note 4)	P _D	1.1	W
			8.8	
Linear derating factor	(Note 5)		1.7	mW/°C
			13.7	
Thermal Resistance, Junction to Ambient	(Note 4)	R _{θJA}	113	°C/W
	(Note 5)		73	
Operating and storage temperature range		T _J , T _{STG}	-55 to 150	°C

- Notes:
4. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 5. Same as note (4), except the device is measured at t ≤ 5 sec.
 6. Same as note (4), except the device is pulsed with D = 0.02 and pulse width 300μs. The pulse current is limited by the maximum junction temperature.

Thermal Characteristics

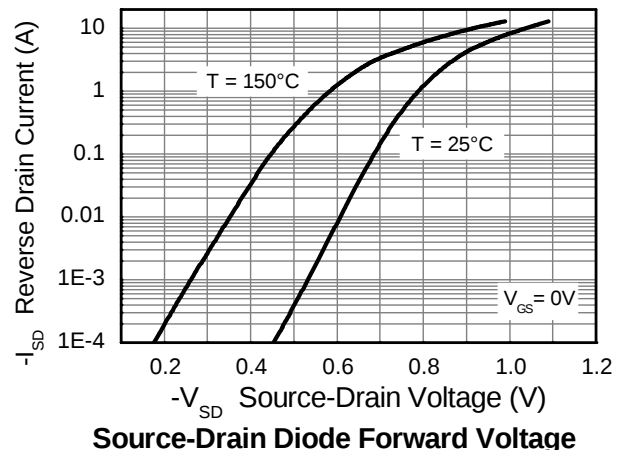
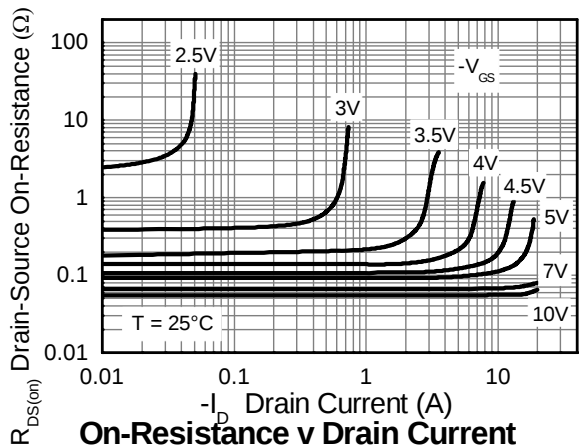
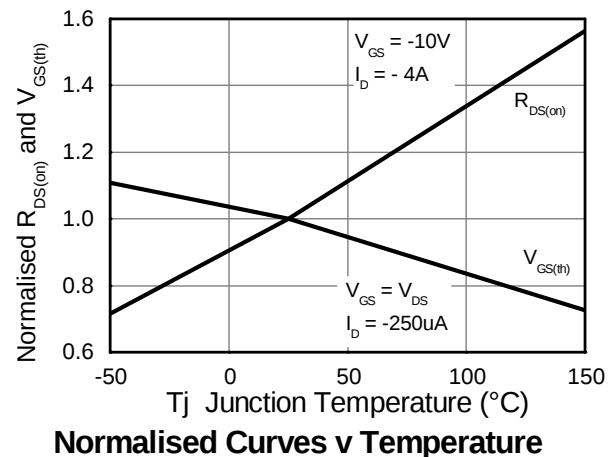
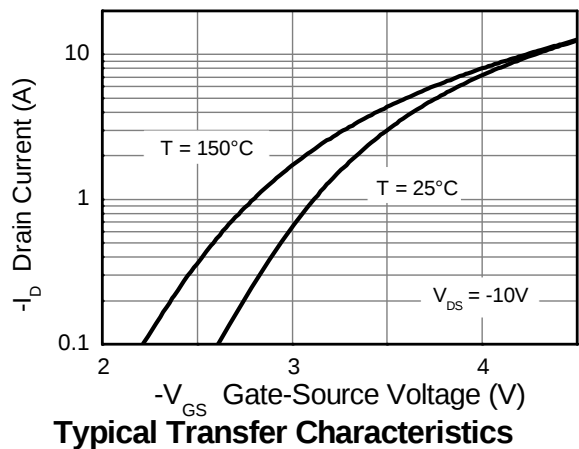
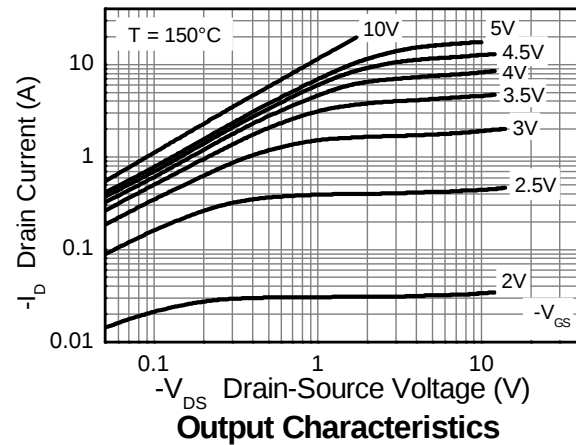
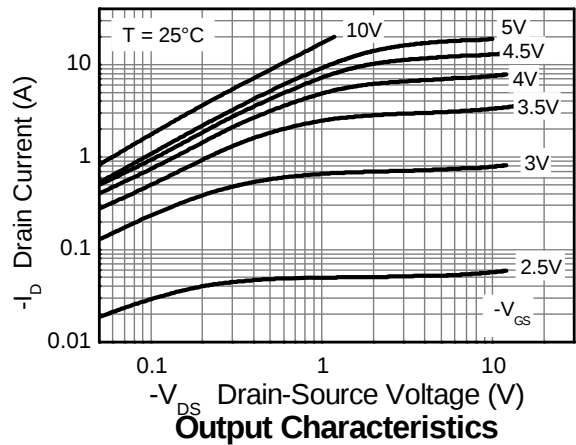


Electrical Characteristics @T_A = 25°C unless otherwise specified

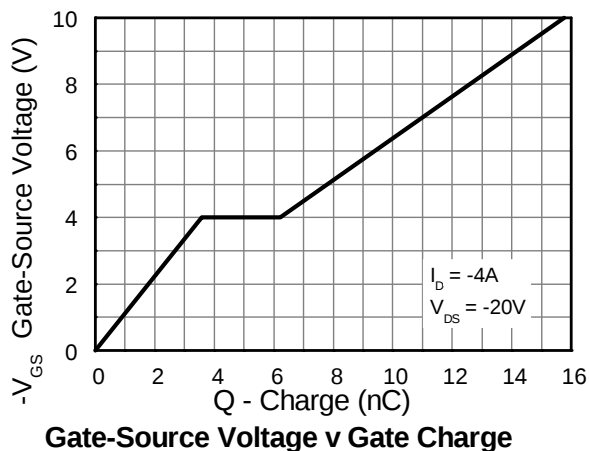
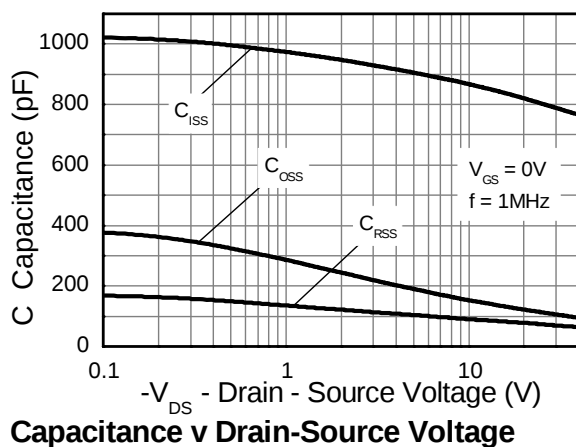
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	-40	—	—	V	I _D = -250μA, V _{GS} = 0V	
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-0.5	μA	V _{DS} = -40V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±20V, V _{DS} = 0V	
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(th)}	-1.0	—	-3.0	V	I _D = -250μA, V _{DS} = V _{GS}	
Static Drain-Source On-Resistance (Note 7)	R _{DS(on)}	—	—	0.080	Ω	V _{GS} = -10V, I _D = -4A	
		—	—	0.150		V _{GS} = -4.5V, I _D = -2A	
Forward Transconductance (Notes 7 & 8)	g _{fs}	—	7.6	—	S	V _{DS} = -15V, I _D = -4A	
Diode Forward Voltage (Note 7)	V _{SD}	—	-0.86	-0.95	V	I _S = -4A, V _{GS} = 0V	
Reverse recovery time (Note 8)	t _{rr}	—	17.4	—	ns	I _S = -1.8A, di/dt = 100A/μs	
Reverse recovery charge (Note 8)	Q _{rr}	—	11.1	—	nC		
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	—	833	—	pF	V _{DS} = -20V, V _{GS} = 0V f = 1MHz	
Output Capacitance	C _{oss}	—	122	—			
Reverse Transfer Capacitance	C _{rss}	—	78	—			
Total Gate Charge (Note 9)	Q _g	—	7	—	nC	V _{GS} = -4.5V	V _{DS} = -20V I _D = -4A
Total Gate Charge (Note 9)	Q _g	—	15.8	—		V _{GS} = -10V	
Gate-Source Charge (Note 9)	Q _{gs}	—	3.6	—			
Gate-Drain Charge (Note 9)	Q _{gd}	—	2.7	—			
Turn-On Delay Time (Note 9)	t _{D(on)}	—	2.5	—	ns	V _{DD} = -20V, V _{GS} = -10V I _D = -1A, R _G ≅ 6.0Ω	
Turn-On Rise Time (Note 9)	t _r	—	3.3	—			
Turn-Off Delay Time (Note 9)	t _{D(off)}	—	47	—			
Turn-Off Fall Time (Note 9)	t _f	—	21	—			

- Notes:
7. Measured under pulsed conditions. Pulse width ≤ 300μs; duty cycle ≤ 2%
 8. For design aid only, not subject to production testing.
 9. Switching characteristics are independent of operating junction temperatures.

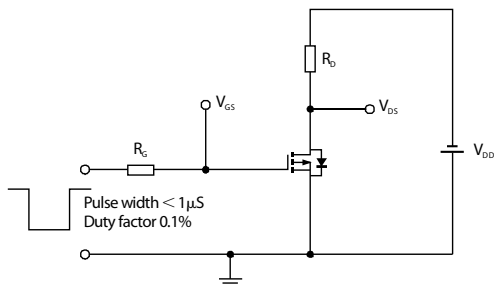
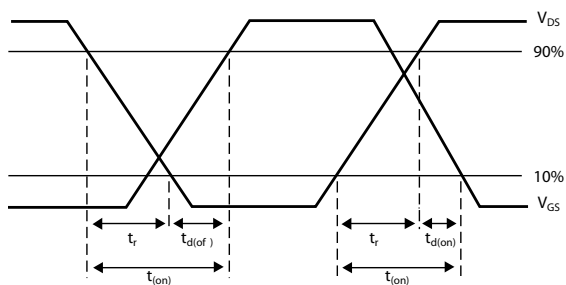
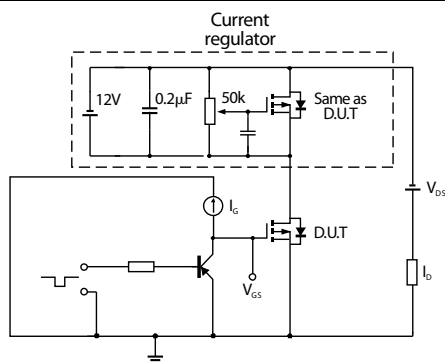
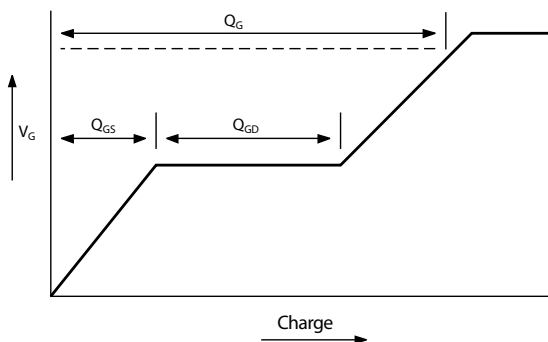
Typical Characteristics



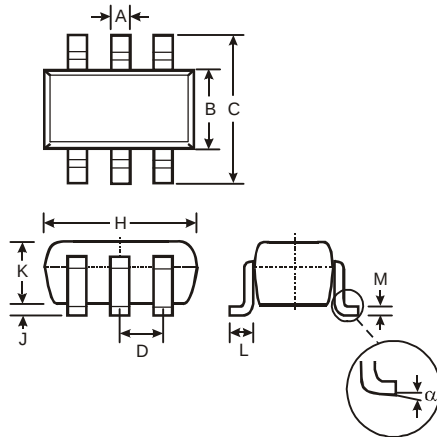
Typical Characteristics - continued



Test Circuits

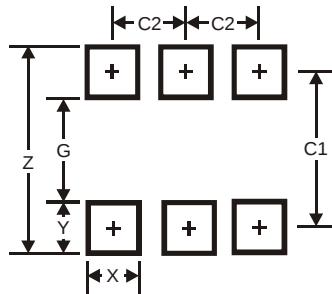


Package Outline Dimensions



SOT-26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

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